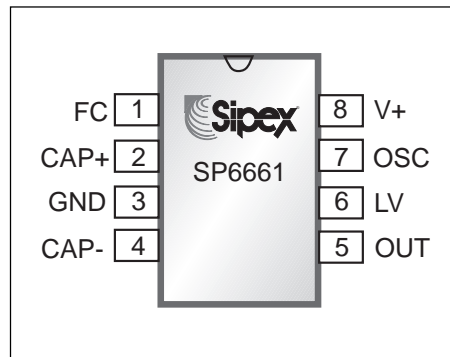



SP6661

High Frequency 200mA Charge Pump Inverter or Doubler

- Inverts or Doubles Input Supply Voltage
- 92% Power Efficiency at 100mA
- 120kHz/900kHz Selectable Oscillator Frequency
- 4.5Ω Output Resistance Using 3.3μF Ceramic Caps
- Low Voltage Battery Operation
- Ideal for 3.6V Lithium Ion Battery or 5.0V Input
- High Output Current – 200mA
- Low Profile Solution
- 1.5V Inverter Startup Guaranteed
- Pin-Compatible High-Current Upgrade of the ICL7660 and 660 Industry Standard
- Smallest Package Available for the 660 Industry Standard – 8 pin μSOIC



DESCRIPTION

The **SP6661** is a CMOS DC-DC Monolithic Voltage Converter that can be implemented as a Voltage Inverter or a Positive Voltage Doubler. As a Voltage Inverter, a -1.5V to -5.0V output can be converted from a +1.5V to +5.0V input. As a Voltage Doubler, a +5.0V to +10.0V output can be provided from a +2.5V to +5.0V input. The **SP6661** is ideal for both battery-powered and board level voltage conversion applications with a typical operating current of 3mA and a high efficiency (>90%) over most of its load-current range. Typical end products for this device are disk drive supplies, operational amplifier and interface power supplies, medical instruments, and hand held and laptop computers. The **SP6661** is available in 8-pin NSOIC, and μSOIC packages.

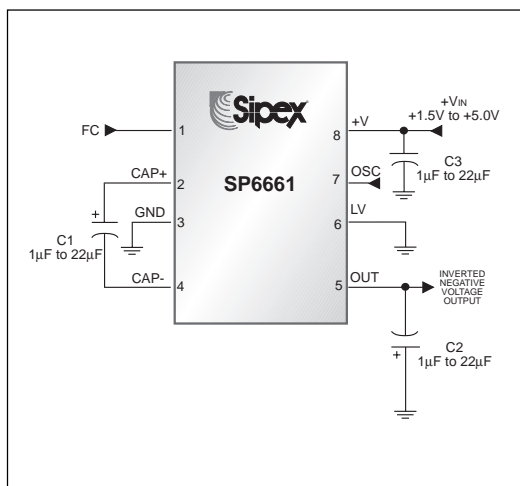


Figure 1: Voltage Inverter

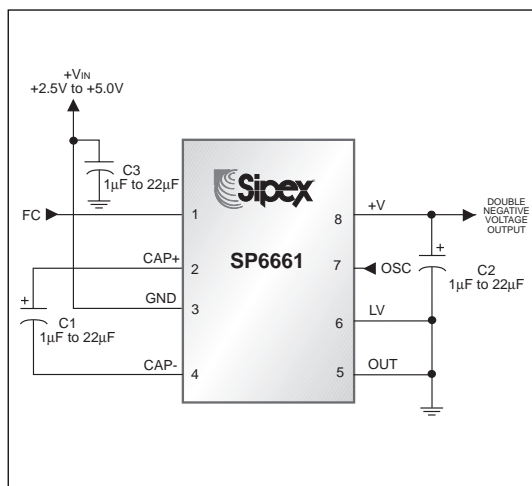


Figure 2: Voltage Doubler

ABSOLUTE MAXIMUM RATINGS

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

Power Supply Voltage
(V+ to GND or GND to OUT).....+5.6V
LV Input Voltages.....(OUT - 0.3V) to (V+ + 0.3V)
FC and OSC Input Voltages.....The least negative of
(OUT - 0.3V) or (V+ - 5.6V) to (V+ + 0.3V)

OUT and V+ Continuous Output Current.....200mA
Output Short-Circuit Duration to GND (Note 1).....1s
Operating Temperature Ranges

SP6661E.....-40°C to +85°C
Continuous Power Dissipation ($T_{AMB} = 70^{\circ}\text{C}$)
NSOIC (derate 5.88mW/°C above +70°C).....471mW
 μ SOIC (derate 4.10mW/°C above +70°C).....330mW
Operating Temperature.....-40°C to +85°C
Storage Temperature.....-65°C to +150°C
Lead Temperature (soldering 10s).....+300°C

SPECIFICATIONS

PARAMETER	MIN.	TYP.	MAX.	UNITS	CONDITIONS
Inverter Circuit at Low Frequency with 22μF Capacitors					
V+ = +5.0V, C1 = C2 = C3 = 22 μ F, FC = open, LV = GND, $T_{AMB} = T_{MIN}$ to T_{MAX} ; refer to <i>Figure 1</i> test circuit. Note 2					
Supply Voltage Range	1.5		5.3	V	$R_L = 500\Omega$
Start-Up Voltage		0.93		V	
Supply Current		3	6	mA	No Load
Output Current	200			mA	
Oscillator Input Current		± 1		μ A	
Oscillator Frequency	70	120	170	kHz	
Output Resistance		5	7	Ω	$I_L = 100\text{mA}$, Note 3
Voltage Conversion Efficiency	99.0	99.9		%	No Load
Power Efficiency	80 70	89 82		%	$I_L = 100\text{mA}$ $I_L = 200\text{mA}$
Doubler Circuit at Low Frequency with 22μF Capacitors					
V+ = +5.0V, C1 = C2 = C3 = 22 μ F, FC = open, LV = GND, $T_{AMB} = T_{MIN}$ to T_{MAX} ; refer to <i>Figure 22</i> test circuit. Note 2					
Supply Voltage Range	2.5		5.3	V	$R_L = 1\text{k}\Omega$
Start-Up Voltage		1.5		V	
Supply Current		3	6	mA	No Load
Output Current	200			mA	
Oscillator Input Current		± 1		μ A	
Oscillator Frequency	70	120	170	kHz	
Output Resistance		4.5	7	Ω	$I_L = 100\text{mA}$, Note 3
Voltage Conversion Efficiency	99.0	99.9		%	No Load
Power Efficiency	89 79	94 90		%	$I_L = 100\text{mA}$ $I_L = 200\text{mA}$

SPECIFICATIONS (continued)

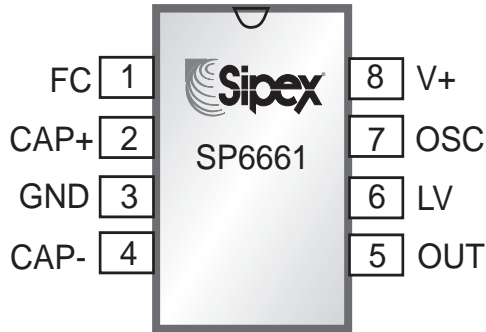
PARAMETER	MIN.	TYP.	MAX.	UNITS	CONDITIONS
Inverter Circuit at High Frequency with 3.3μF Capacitors					
V ₊ = +5.0V, C1 = C2 = C3 = 3.3 μ F, FC = V ₊ , LV = GND, T _{AMB} = T _{MIN} to T _{MAX} ; refer to <i>Figure 1</i> test circuit. Note 2					
Supply Voltage Range	1.5		5.3	V	R _L = 500 Ω
Start-Up Voltage		0.93		V	
Supply Current		10	18	mA	No Load
Output Current	200			mA	
Oscillator Input Current		± 8		μ A	
Oscillator Frequency	500	900	1250	kHz	
Output Resistance		5	7	Ω	I _L = 100mA, Note 3
Voltage Conversion Efficiency	99.0	99.6		%	No Load
Power Efficiency	78 65	84 79		%	I _L = 100mA I _L = 200mA
Doubler Circuit at High Frequency with 3.3μF Capacitors					
V ₊ = +5.0V, C1 = C2 = C3 = 3.3 μ F, FC = V ₊ , LV = GND, T _{AMB} = T _{MIN} to T _{MAX} ; refer to <i>Figure 2</i> test circuit. Note 2					
Supply Voltage Range	2.5		5.3	V	R _L = 1k Ω
Start-Up Voltage		1.5		V	
Supply Current		10	18	mA	No Load
Output Current	200			mA	
Oscillator Input Current		± 8		μ A	
Oscillator Frequency	500	900	1250	kHz	
Output Resistance		4.5	7	Ω	I _L = 100mA, Note 3
Voltage Conversion Efficiency	99.0	99.9		%	No Load
Power Efficiency	87 79	92 89		%	I _L = 100mA I _L = 200mA

NOTE 1: Specified output resistance is a combination of internal switch resistance and capacitor ESR.

NOTE 2: In the test circuit capacitors C1, C2 and C3 are 22 μ F, 0.05 maximum ESR, ceramic or 3.3 μ F, 0.05 Ω maximum ESR, ceramic. Capacitors with higher ESR may reduce output voltage and efficiency. Refer to Capacitor Selection section.

NOTE 3: Specified output resistance is a combination of internal switch resistance and capacitor ESR. Refer to Capacitor Selection section.

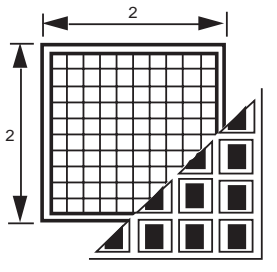
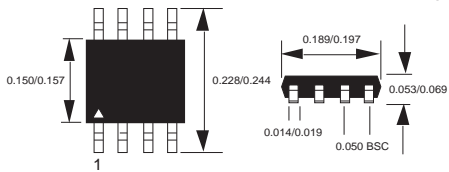
PINOUT



PIN ASSIGNMENTS

Pin Number	Pin Symbol	Description
1	FC	Frequency Control for the internal oscillator. FC = open, $f_{osc} = 120\text{kHz}$ typical; FC = V+ $f_{osc} = 900\text{kHz}$ typical.
2	CAP+	Connect to the positive terminal of the charge pump capacitor.
3	GND	(Voltage Inverter Circuit) Ground.
3	GND	(Positive Voltage Doubler Circuit) Positive supply voltage input.
4	CAP-	Connect to the negative terminal of the charge pump capacitor.
5	OUT	(Voltage Inverter Circuit) Negative voltage output pin.
5	OUT	(Positive Voltage Doubler Circuit) Ground pin for power supply.
6	LV	Low -voltage operation input pin in 660 circuits. In SP6661 circuits can be connected to GND, OUT or left open as desired with no effect.
7	OSC	Control pin for the oscillator. Internally connected to 15pF capacitor. An external capacitor can be added to slow the oscillator. Be careful to minimize stray capacitance. An external oscillator can be connected to overdrive the OSC pin.
8	V+	(Voltage Inverter Circuit) Positive voltage input pin for the power supply.
8	V+	(Positive Voltage Doubler Circuit) Positive voltage output.

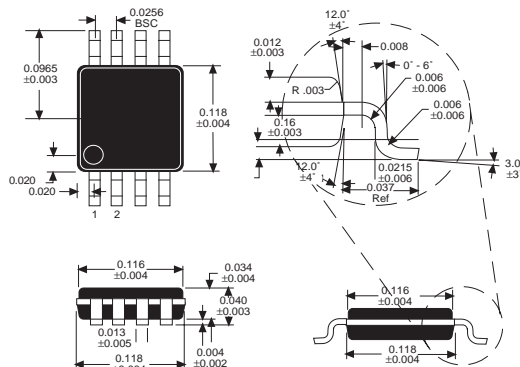
All package dimensions in inches



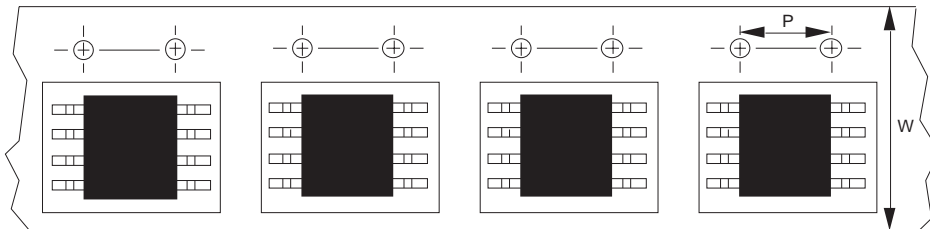
100 die per waffle pack



95 NSOIC devices per tube, no minimum quantity



50 μ SOIC devices per tube



8-pin NSOIC 13" reels: P = 8mm, W = 12mm

pkg	min qty per reel	std qty per reel	max qty per reel
CN	500	1500	2500
CU	500	1500	3000

ORDERING INFORMATION

Part Number	Temperature Range	Package Type
SP6661EN	-40°C to +85°C	8-Pin NSOIC
SP6661EN/TR	-40°C to +85°C	8-Pin NSOIC
SP6661EU	-40°C to +85°C	8-Pin μ SOIC
SP6661EU/TR	-40°C to +85°C	8-Pin μ SOIC
SP6661UEB		8-Pin μ SOIC Evaluation Board



SIGNAL PROCESSING EXCELLENCE

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